IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

Dan Botez, et al.

Date:

January 30, 2001

Docket No.: 032026:0570

HIGH PEAK CURRENT DENSITY RESONANT TUNNELING DIODE For:

PRELIMINARY AMENDMENT

Box ISSUE FEE Commissioner for Patents Patent and Trademark Office Washington, DC 20231

Dear Sir:

With respect to the accompanying application, please amend the application in the specification on page 1, after the title, and before "Field of the Invention", by inserting the following paragraph:

-- This invention was made with United States government support awarded by the following agency: AFOSR Grant #: AGR DTD 09/12/95. The United States has certain rights in this invention .--

REMARKS

The foregoing Amendment adds reference to government rights and does not add any new matter to the application. Entry of the amendment is thus respectfully requested.

Respectfully Submitted,

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